Electronic structure of the delafossite-type $CuMO_2$ (M = Sc, Cr, Mn, Fe, and Co): Optical absorption measurements and first-principles calculations

Hiroki Hiraga,¹ Takayuki Makino,^{2,*} Tomoteru Fukumura,^{3,4} Hongming Weng,^{5,6} and Masashi Kawasaki^{1,2,7,8}

¹WPI Advanced Institute for Materials Research, Tohoku University, Sendai 980-8577, Japan

²Correlated Electron Research Group (CERG), RIKEN Advanced Science Institute (ASI), Wako 351-0198, Japan

³Department of Chemistry, University of Tokyo, Tokyo 113-0033, Japan

⁴PRESTO, Japan Science and Technology Agency, Saitama 332-0012, Japan

⁵Research Center for Integrated Science, Japan Advanced Institute of Science and Technology, Ishikawa 923-1292, Japan

⁶Institute of Physics, Chinese Academy of Sciences, Beijing 100190, China

⁷Quantum Phase Electronics Center and Department of Applied Physics, University of Tokyo, Tokyo 113-8656, Japan

⁸CREST, Japan Science and Technology Agency, Tokyo 102-0075, Japan

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We compared the results of first-principles calculations with measured absorption spectra in thin films of delafossite-type CuMO₂ (M = Sc, Cr, Mn, Fe, and Co) taken at 10 K. Two optical transitions were found: one is associated with Cu3d + O2p \rightarrow Cu3d_{z²} + 4s observed in all of the CuMO₂ films, and the other is associated with Cu3d + O2p \rightarrow M3d detected for M = Mn, Fe, and Co. The energy of the former transition showed an unexpected dependence on the atomic number of M. An abrupt change of this energy occurs for M = Cr, which is explained as a result of the interaction between the Cu3d_{z²} + 4s and M3d bands.

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The delafossite cuprous compound $CuMO_2$ is known to exhibit intriguing properties depending on trivalent metal elements M, such as excitonic effects¹ in $CuScO_2$, p-type conductivity² in $CuAIO_2$, and multiferroicity with ferroelectricity and ferromagnetism^{3,4} in $CuCrO_2$ and $CuFeO_2$. Their electronic structures have to be systematically studied for a deeper understanding of their properties.

We used this to examine the influence of 3d orbital occupancy of transition metals (TM) on properties in CuMO₂. The optical transitions (E_g^B) appear in the visible region due to charge-transfer (CT) excitations to the TM 3d orbitals, as observed in LaMO₃,⁵ Sr₂MO₄,⁶ and CuMO₂.⁷⁻⁹ In LaMO₃, the TM-related gap energy decreased with an increase in atomic numbers from Cr to Ni, the dependence of which has been explained in terms of atomic ionization energies and of Madelung potentials.⁵ There is an optical gap (E_g^A) in the higher energy region for CuMO₂, attributed to *dipole-allowed* $Cu3d + O2p \rightarrow Cu3d_{z^2} + 4s$ transition.¹ This is in contrast to Cu_2O ,¹⁰ which is *dipole forbidden*. The layered structure can be viewed as a natural superlattice composed of Cu₂O dumbbells and the wider band-gap insulator M_2O_3 as shown in the inset of Fig. 1 (M = Sc). In the naturally low-dimensional structure, hybridization of Cu and O orbitals^{2,11} results in a direct gap¹ accompanied by an excitonic effect.¹

In this work, the interaction between excitons and *d*-orbital ions was studied for CuMO₂ (M = Sc, Cr, Mn, Fe, and Co) at 10 K by absorption spectroscopy. Such an interaction was investigated in diluted magnetic semiconductors^{12,13} such as Cd_{1-x} M_x Te (M = Cr, Mn, Fe, and Co), with magnetic polaron effects. There has been no study on the effect of *quasi-low-dimensional* excitons. An anomalous *M*-element dependence of the E_g^A energy was found, and this dependence was explained by first-principles calculations in terms of the relative positions of *M*3*d* and Cu3*d*_{z²} + 4*s* bands.

CuMO₂ thin films were grown on MgAl₂O₄ (111) substrates (cubic structure with a = 8.083 Å) and sapphire (0001)

substrates (hexagonal structure with a = 4.759 Å and c = 12.993 Å) using a pulsed laser deposition.¹⁴ Highly crystalline films were obtained on MgAl₂O₄ substrates for M = Sc and Mn,^{1,7} whereas sapphire gave rise to better crystallinity in M = Cr, Fe, and Co. These substrates were prepared to be atomically flat by annealing in a furnace. A hot-press method was used to prepare targets for M = Mn and Fe (M = Sc, Cr, and Co). To determine the crystallographic data, powder x-ray diffraction (XRD) and high-resolution four-circle XRD were used for 150-nm-thick films. Optical absorption spectra were measured at 10 K.

Figure 1 shows reciprocal space maps of XRD around $(10\overline{1}\underline{14})$ of CuMO₂ (M = Cr, Fe, and Co) having a trigonal structure and sapphire ($20\overline{2}10$) asymmetric diffractions. Mismatches of the hexagonal unit cell parameters between bulk and thin films were as small as 1.2%, ^{15,16} indicating that the film lattices are relaxed. The x-ray pole figures for the ($10\overline{18}$) diffraction peak of CuMO₂ and ($10\overline{12}$) of the sapphire substrate revealed two domains with in-plane 60° rotation. This is consistent with the previously observed features for a CuGaO₂ on sapphire.¹⁷ The films have single phases without other impurity phases. Crystallographic data of CuMO₂ films (M = Sc and Mn) are found elsewhere.^{1,7} The inset shows a typical crystal structure and epitaxial relationship of the film to the substrate. Perpendicular to the plane, the octahedral is connected by a Cu-O-Cu dumbbell structure.¹

The absorption spectra were analyzed by first-principles calculations in which the accurate all-electron full-potential literalized augmented plane-wave method implemented in WIEN2k package was used.¹⁵ To describe the 3*d* electrons correctly, on-site Coulomb interaction is treated by a generalized gradient approximation +U (GGA+U) method. Despite its chemical trend, we used a value of U independent of M for simplicity. The use of U = 4.0 eV gave results compared reasonably well with experimental data. The experimental geometrical structure was used for calculation. Despite its

Sc3d

ΡĒ



FIG. 1. (Color online) Reciprocal space contour map around $CuMO_2$ (10114) and sapphire (20210) diffractions. Crosses denote the corresponding peak positions for the bulk compounds. Inset shows the epitaxial relationship and definitions of the respective indices.

noncollinear magnetic ordering of $CuCrO_2$, we take, the antiferromagnetic ordering¹⁹ as measured in CuFeO₂. For CuMnO₂, the experimental antiferromagnetic ordering⁷ is used for calculation.

Experimental absorption spectra are shown by solid lines in Fig. 2 for $CuMO_2$ films. The absorption is negligible below a sharp peak "A" in CuScO₂ and CuCrO₂, while there are discernible peaks "B1" and "B2" and an absorption tail "C" for the other compounds (M = Mn, Fe and Co). A better understanding of the difference in characters of peaks requires insights into their electronic structures. We drew a schematic energy-level diagram from our first-principles calculations as shown in the right panel of Fig. 2. Starting from the lowermost trace for M = Sc and Cr, the transition Cu3d + $O2p \rightarrow$ unoccupied M3d states has a larger energy than that of the Cu3d + O2p \rightarrow Cu3d_{z²} + 4s gap. The latter transition can be found as a common absorption peak of "A," related to the excitation in Cu-O-Cu structures. Such a low-dimensional structure leads to the van Hove singularity in density of states for both valence and conduction bands, as shown by "Cu3d" in Fig. 3(a). This can account partially for the narrow width of this peak. Here, not only the Cu4s but also the $Cu3d_{z^2}$ orbitals contribute to the conduction band minima (CBM) due to the hybridization effect. This



FIG. 2. (Color online) Absorption spectra (solid lines) of $CuMO_2$ (M = Sc, Cr, Mn, Fe, and Co) thin films measured at 10 K. Dashed lines represent fits to the experimental data based on a modified Elliott model, with a baseline (a dash-dotted line). Schematic energy diagrams, concluded from first-principles calculations, are shown in the right panel. Arrows indicate transitions corresponding to the observed absorption peaks.

4

5

M = Sc

2

3

E(eV)

0

is because the actual charge state of Cu ions is slightly larger than +1, being the formal charge state of CuMO₂. The absorption peak "A" is assigned to exciton states with the quantum number of n = 1, followed by higher-lying continuum absorption,²⁰ we evaluate their binding energies. Because of ambiguity in determining the energy of the continuum, we analyzed the line shape based on a modified Elliott model¹ by relying on the exciton energy, the absorption coefficients at the n = 1 state, and at the continuum.²¹ The results of fitting are shown by dashed lines in Fig. 2 with a baseline determined by contributions from other peaks. The excitonic binding energies are 380, 330, 520, 450, and 320 meV for M = Sc, Cr, Mn, Fe, and Co, respectively. All the values are larger than that of Cu_2O (150 meV)¹⁰ and approximately proportional to the energy E_{σ}^{A} . we define the *absorption peak* energy as E_{σ}^{A} .

The peaks B_1 and B_2 are assigned to the *M*-related transition of $Cu3d + O2p \rightarrow M3d$ or *d*-*d* transition of *M3d*. They are similar to the CT excitation from O2p to *M3d* upper Hubbard states with its ligand field splitting in the 3*d* orbital as observed in La MO_3 .⁵ The excitons do not seem to affect on



FIG. 3. (Color online) Density of states (left panel) and band structure (right panel) of CuCrO₂ (a) and CuFeO₂ (b) deduced from GGA+U (U = 4.0 eV) calculations. Arrows indicates interband transitions corresponding to the absorption peaks shown in Fig. 2. Note that the density of states for Cu3 d_z^2 + 4s is magnified for clarification.

the line shapes because they are close to that of first-principles calculations. The energies of tails C correspond to those of the lowest band gaps (E_g^C) .

The electronic structure of CuCrO₂ is straightforward as shown in Fig. 3(a). The film has absorption at $E_g^A = 3.56$ eV, because the occupied t_{2g} and the empty e_g levels of Cr³⁺ are energetically far away from the valence band maximum (VBM) and the CBM, respectively. Unlike previous studies,^{22,23} other lower-lying transitions were not observed in our films, due to the single-phase nature and high orientation of the films.

In CuMnO₂, the lowest unoccupied band is mainly the Mn $d_{x^2-y^2}$ orbital because of Jahn-Teller splitting of the e_g band in Mn³⁺, where three electrons are in spin majority t_{2g} bands, and one is in the spin majority d_{z^2} orbital. The Cu $3d_z^2 + 4s$ orbitals are higher than the Mn $d_{x^2-y^2}$ orbitals and mixed with the *spin minority* Mn t_{2g} states. The *spin minority* Mn e_g states are in a higher level. The two lowerlying peaks B₂ at 3.0 eV and B₁ at 3.7 eV are assigned to CT excitations to the above-mentioned final states, i.e., Cu $3d + O2p \rightarrow Mn d_{x^2-y^2} (E_g^{B2})$ and Cu $3d + O2p \rightarrow Mn t_{2g} (E_g^{B1})$, respectively.

In CuFeO₂, four absorption peaks were identified at 4.38 (A), 3.85 (B₁), 2.80 (B₂), and 1.55 (C) eV. According to the calculated band structure shown in Fig. 3(b), B₁ and B₂ are assigned to the transitions of Cu3d + O2p \rightarrow Fe e_g



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FIG. 4. (Color online) Transition energies, E_g^A , E_g^{B1} , E_g^{B2} , and E_g^C , of absorption spectra shown in Fig. 2 are plotted against the number of 3*d* electrons in M^{3+} ions of CuMO₂ (M = Sc, Cr, Mn, Fe, and Co) thin films. Closed circles indicate experimental values, and open triangles refer to the first-principles calculation results. An abrupt change occurs in E_g^A between CuCrO₂ and CuMnO₂.

and of $Cu3d + O2p \rightarrow Fe t_{2g}$. These peak energies are higher than those reported in the literature.^{9,24} The previous values have been determined from photo-electrochemical spectra. The interpretation of such a spectrum is complex, leading to an inaccurate estimate.

TM-related absorption peaks were also observed in CuCoO₂. Our band structure calculations indicated that the Co³⁺ ions are in a nonmagnetic state with fully occupied t_{2g} orbitals and empty e_g orbitals, which is consistent with a previous report on magnetic properties.²⁴ The fully occupied t_{2g} orbitals are located about 1.0–2.0 eV below the highest occupied Cu3*d* + O2*p* orbitals, i.e., VBM. The empty e_g orbitals are located ~2.0 eV higher than the VBM and ~1.5 eV lower than the CBM. Therefore, the B₂ peak is assigned to transition of Cu3*d* + O2*p* \rightarrow Co e_g . The assignment of B₁ is associated with the Co *d*-*d* transition inside Co3*d* ($t_{2g} \rightarrow e_g$) ions. The *d*-*d* optical transition may be partially dipole allowed due to a lower symmetry of the delafossite structure.²⁶

Figure 4 shows experimental values of the energies E_g^A , E_g^{B1} , E_g^{B2} , and E_g^C along with the theoretical E_g^A and E_g^C . The energies E_g^{B1} and E_g^{B2} decrease monotonically from M = Mn to Co. This chemical trend is consistent with that in La MO_3 , explained in terms of chemical trends of the atomic ionization energies and of Madelung potentials.⁵ There is an abrupt jump in E_g^A (a red line in Fig. 4) at M = Cr despite the same origin for the relevant transition.

The reason for the jump in E_g^A is understood from the electronic structure diagram shown in Fig. 2. The position of the Cu₃d_{z²} + 4s orbital is influenced by the unoccupied *M*₃d orbitals having an apparent chemical trend, which results in the above-mentioned *M*-dependence of E_g^A . Let us discuss the electronic structures of CuMO₂ around the jump, i.e., CuCrO₂

and CuFeO₂. CuMnO₂ was not adopted for this comparison because of the different crystal system (monoclinic).^{7,27} As shown in Fig. 3(a), the unoccupied *d* orbital of Cr3*d* lies higher in energy than Cu3*d*_{z²} + 4*s* bands, resulting in Cu3*d*_{z²} + 4*s* bands being pushed downward. The unoccupied *d* orbitals are located lower than Cu3*d*_{z²} + 4*s* bands later 3*d* elements such as Mn, Fe, and Co, resulting in the latter band being pushed higher. Repulsive interaction between the two bands determines the position of the CBM, while the VBM remains unchanged. The energy of E_g^A in CuCrO₂ is significantly smaller than that in CuFeO₂, as shown by arrows with "A" in the left panels of Fig. 3. The theoretical calculations support this interpretation; the E_g^A are in agreement with experiments as shown in Fig. 4.

The optical properties of $CuMO_2$ are characterized by strong interaction between 3*d* electrons and excitons. These materials can thus be regarded as a suitable system to investigate the excitonic effect on photo-induced spin dynamics. It should be noted that the importance of Coulomb interaction for photo-dynamics has been recently pointed out even in ferromagnetic metals. $^{\mbox{$28$}}$

In summary, we measured absorption spectra in CuMO₂ (M = Sc, Cr, Mn, Fe, and Co) at 10 K. Absorption peaks corresponding to the excitonic transition between Cu3d + O2p and Cu3 $d_{z^2} + 4s$ bands were commonly observed. CT and d-d transitions involving 3d orbitals of M were identified. The results of first-principles calculations systematically explain the energy positions of the above-mentioned transitions as a function of M taking into account the relative positions between Cu3 $d_z^2 + 4s$ and M3d bands.

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*tmakino@riken.jp

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